











OPA827

SBOS376I - NOVEMBER 2006-REVISED JULY 2016

OPA827 Low-Noise, High-Precision, JFET-Input Operational Amplifier

1 Features

 Input Voltage Noise Density: 4 nV/√Hz at 1 kHz

Input Voltage Noise:
 0.1 Hz to 10 Hz: 250 nV_{PP}

Input Bias Current: 10 pA (Maximum)
 Input Offset Voltage: 150 µV (Maximum)
 Input Offset Drift: 2 µV/°C (Maximum)

Gain Bandwidth: 22 MHzSlew Rate: 28 V/µs

Quiescent Current: 4.8 mA/Ch
 Wide Supply Range: ±4 V to ±18 V
 Packages: 8-Pin SOIC and 8-Pin VSSOP

2 Applications

ADC Drivers

DAC Output Buffers

Test Equipment

Medical Equipment

PLL Filters

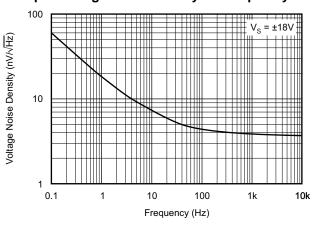
Seismic Applications

Transimpedance Amplifiers

Integrators

Active Filters

Input Voltage Noise Density vs Frequency



3 Description

The OPA827 series of JFET operational amplifiers combine outstanding DC precision with excellent AC performance. These amplifiers offer low offset voltage (150 μ V, maximum), very low drift over temperature (0.5 μ V/°C, typical), low-bias current (3 pA, typical), and very low 0.1-Hz to 10-Hz noise (250 nV_{PP}, typical). The device operates over a wide supply voltage range, ±4 V to ±18 V on a low supply current (4.8 mA/Ch, typical).

Excellent AC characteristics, such as a 22-MHz gain bandwidth product (GBW), a slew rate of 28 V/µs, and precision DC characteristics make the OPA827 series well-suited for a wide range of applications including 16-bit to 18-bit mixed signal systems, transimpedance (I/V-conversion) amplifiers, filters, precision ±10-V front ends, and professional audio applications.

The OPA827 is available in both 8-pin SOIC and 8-pin VSSOP surface-mount packages, and is specified from -40°C to 125°C.

Device Information(1)

| PART NUMBER | PACKAGE | BODY SIZE (NOM) | | |
|-------------|-----------|-------------------|--|--|
| OD4927 | SOIC (8) | 4.90 mm × 3.91 mm | | |
| OPA827 | VSSOP (8) | 3.00 mm × 3.00 mm | | |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

0.1-Hz to 10-Hz Noise

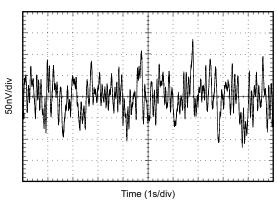




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| CI | nanges from Revision H (May 2012) to Revision I | Page |
|----------|---|-----------|
| • | Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section | 1 |
| • | Deleted Package/Ordering Information table, see POA at the end of the data sheet | 4 |
| • | Changed values in the <i>Thermal Information</i> table to align with JEDEC standards | 5 |
| CI | nanges from Revision G (February 2012) to Revision H | Page |
| • | Updated Figure 3 | 8 |
| <u>.</u> | Updated Figure 4 | <u> 8</u> |
| CI | nanges from Revision F (March 2009) to Revision G | Page |
| • | Changed Input bias current and Input offset drift Features bullets | 1 |
| • | Changed product status from Mixed Status to Production Data | 1 |
| • | Changed description of amplifier drift and bias current in first paragraph of Description section | 1 |
| • | Deleted high grade (OPA827I) option and footnote 2 from Package/Ordering Information table | 4 |
| • | Deleted high grade (OPA827I) option from Electrical Characteristics table | 6 |
| • | Changed Offset Voltage, <i>Input Offset Voltage Drift</i> parameter typical and maximum specifications in Electrical | |

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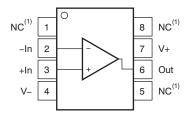
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5 Pin Configuration and Functions

D and DGK Packages 8-Pin SOIC and VSSOP Top View



(1) NC denotes no internal connection.

Pin Functions

| | PIN | 1/0 | DESCRIPTION | | | |
|-----|---------|-----|---|--|--|--|
| NO. | NAME | I/O | DESCRIPTION | | | |
| +IN | 3 | 1 | Noninverting input | | | |
| -IN | 2 | 1 | Inverting input | | | |
| NC | 1, 5, 8 | _ | No internal connection (can be left floating) | | | |
| OUT | 6 | 0 | Output | | | |
| V+ | 7 | _ | Positive power supply | | | |
| V- | 4 | _ | Negative power supply | | | |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | MIN | MAX | UNIT |
|---------------------------------------|------------|-----------------|------|
| Supply voltage, $V_S = (V+) - (V-)$ | | 40 | V |
| Input voltage ⁽²⁾ | (V-) - 0.5 | (V+) + 0.5 | V |
| Input current ⁽²⁾ | | ±10 | mA |
| Differential input voltage | | ±V _S | V |
| Output short-circuit ⁽³⁾ | Contin | nuous | |
| Operating temperature, T _A | -55 | 150 | °C |
| Junction temperature, T _J | | 150 | °C |
| Storage temperature, T _{stg} | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| V | Flootroototic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±4000 | \/ |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±1000 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM MAX | UNIT |
|----------------|-----------------------|-----|---------|------|
| Vs | Supply voltage | ±4 | ±18 | V |
| T _A | Specified temperature | -40 | 125 | °C |

6.4 Thermal Information

| | | OP | | |
|----------------------|--|----------|-------------|------|
| | THERMAL METRIC ⁽¹⁾ | D (SOIC) | DGK (VSSOP) | UNIT |
| | | 8 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 160 | 180 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 75 | 55 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 60 | 130 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 9 | | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 50 | 120 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | _ | _ | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails must be current-limited to 10 mA or less.

⁽³⁾ Short-circuit to V_S/2 (ground in symmetrical dual-supply setups).

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

at $V_S = \pm 4$ V to ± 18 V, $T_A = 25$ °C, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------------|---|----------|-----------------------|----------|--------------------|
| OFFSET VOL | TAGE | | | | | |
| Vos | Input offset voltage | $V_S = \pm 15 \text{ V}, V_{CM} = 0 \text{ V}$ | | 75 | 150 | μV |
| dV _{OS} /dT | Input offset voltage drift | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | 0.1 | 2 | μV/°C |
| DODD | Input offset voltage vs power | | | 0.2 1 | | \/\/ |
| PSRR | supply | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | 3 | μV/V |
| INPUT BIAS C | CURRENT | | | | | |
| | | | | ±3 | ±10 | pA |
| I_{B} | Input bias current | $T_A = -40$ °C to 85°C | | | ±500 | pA |
| | | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | ±5 | nA |
| Ios | Input Offset Current | | | ±3 | ±10 | pA |
| NOISE | | | | | | |
| | Input Voltage Noise: | $f = 0.1 \text{ Hz to } 10 \text{ Hz}, V_S = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$ | | 250 | | nV_{PP} |
| e _n | Innut Valta an Naine Dannitu | $f = 1 \text{ kHz}, V_S = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$ | | 4 | | ->//-/ |
| | Input Voltage Noise Density | f = 10 kHz, V _S = ±18 V, V _{CM} = 0 V | 3.8 | | nV/√Hz | |
| i _n | Input current noise density | f = 1 kHz, V _S = ±18 V, V _{CM} = 0 V | | 2.2 | | fA/√ Hz |
| INPUT VOLTA | AGE RANGE | | | | | |
| V _{CM} | Common-mode voltage range | | (V-) + 3 | | (V+) - 3 | V |
| | | $(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S < 10 V$ | 104 | 114 | | |
| | | $(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S \ge 10 V$ | 114 | 126 | | |
| CMRR | Common-mode rejection ratio | $(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S < 10 V$ $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$ | 100 | | | dB |
| | | $(V-) + 3 V \le V_{CM} \le (V+) - 3 V, V_S \ge 10 V$ $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$ | 110 | | | |
| INPUT IMPED | ANCE | | | | | |
| Differential | | | | 10 ¹³ 9 | | Ω pF |
| Common-mode | e | | | 10 ¹³ 9 | | Ω pF |
| OPEN-LOOP | GAIN | | 1 | | | |
| | | $(V-) + 3 V \le V_O \le (V+) - 3 V, R_L = 1 k\Omega$ | 120 | 126 | | |
| A _{OL} | Open-loop voltage gain | $(V-) + 3 V \le V_O \le (V+) - 3 V$, $R_L = 1 k\Omega$ $T_A = -40$ °C to 125°C | 114 | | | dB |
| FREQUENCY | RESPONSE | | 1 | | | |
| GBW | Gain-bandwidth product | G = +1 | | 22 | | MHz |
| SR | Slew rate | G = -1 | 20 | 28 | | V/µs |
| | | ±0.01%, 10-V step, G = -1, C _L = 100 pF | | 550 | | ns |
| t _S | Settling time | 0.00075% (16-bit), 10-V step, G = -1, C _L = 100 pF | | 850 | | ns |
| | Overload recovery time | Gain = -10 | | 150 | | ns |
| TUD.N | Total Harmonic Distortion + | G = +1, f = 1 kHz | | 0.00004% | | |
| THD+N | Noise | $V_O = 3 V_{RMS}, R_L = 600 \Omega$ | | -128 | | dB |



Electrical Characteristics (continued)

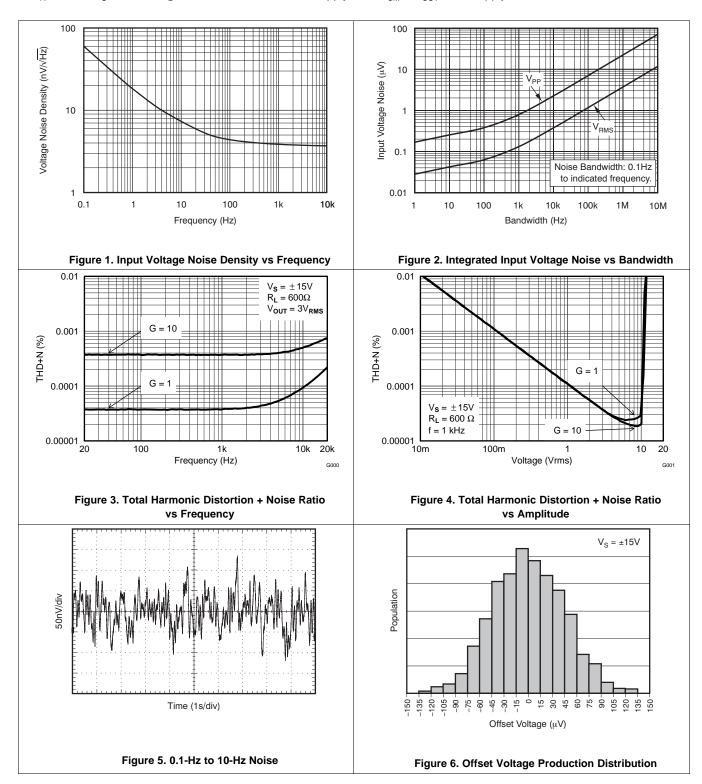
at $V_S = \pm 4$ V to ± 18 V, $T_A = 25$ °C, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP MAX | UNIT | |
|-------------------|----------------------------|---|------------|-----------------------------|------|--|
| OUTPUT | | · | | | | |
| | | $R_L = 1 \text{ k}\Omega, A_{OL} > 120 \text{ dB}$ | (V-) + 3 | (V+) - 3 | | |
| | Voltage output swing | $R_L = 1 \text{ k}\Omega, A_{OL} > 114 \text{ dB}$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | (V-) + 3 | (V+) – 3 | V | |
| I _{OUT} | Output current | V _S - V _{OUT} < 3 V | | 30 | mA | |
| I _{SC} | Short-circuit current | | ±55 | ±65 | mA | |
| C _{LOAD} | Capacitive load drive | | See Typica | al Characteristics | | |
| Z _O | Open-loop output impedance | | See Typica | See Typical Characteristics | | |
| POWER SUI | PPLY | | · | · | | |
| V _S | Specified voltage | | ±4 | ±18 | V | |
| | Quiescent current | I _{OUT} = 0A | | 4.8 5.2 | A | |
| IQ | (per amplifier) | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | 6 | mA | |

TEXAS INSTRUMENTS

6.6 Typical Characteristics

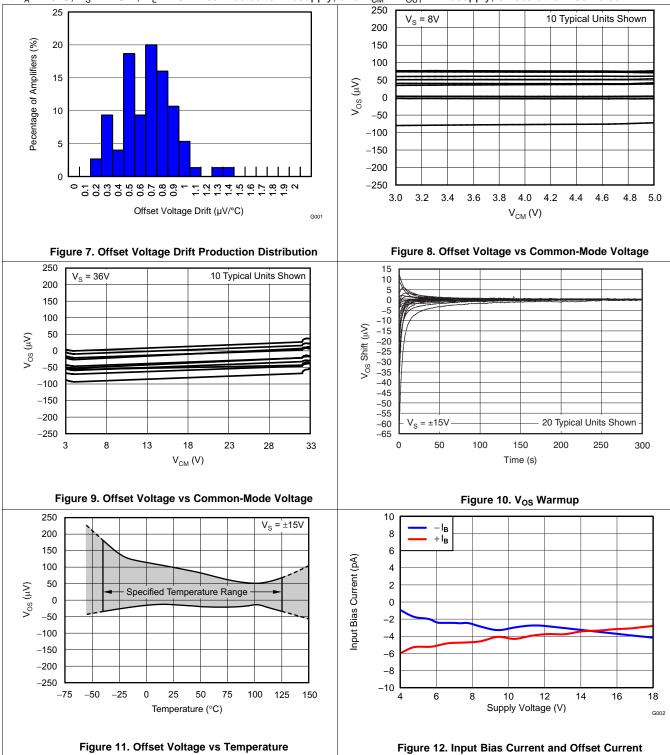
At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.





Typical Characteristics (continued)





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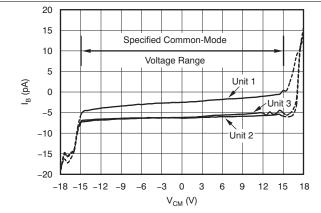
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vs Supply Voltage

TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



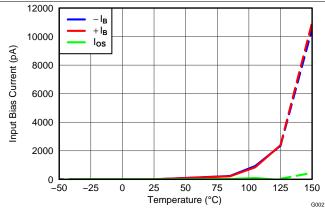
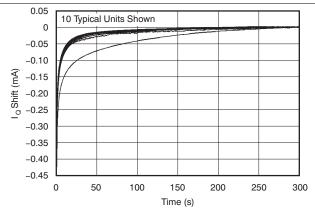


Figure 13. Input Bias Current vs Common-Mode Voltage

Figure 14. Input Bias Current vs Temperature



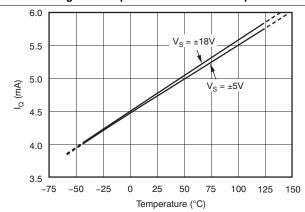
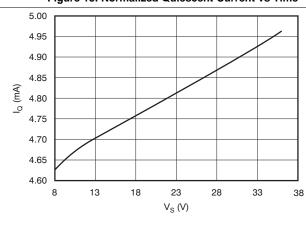


Figure 15. Normalized Quiescent Current vs Time

Figure 16. Quiescent Current vs Temperature



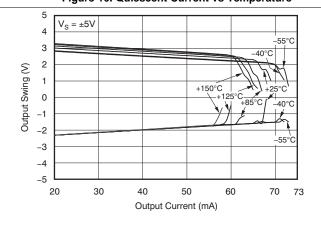


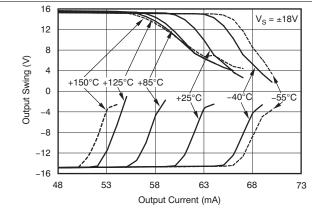
Figure 17. Quiescent Current vs Supply Voltage

Figure 18. Output Voltage Swing vs Output Current



Typical Characteristics (continued)

At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



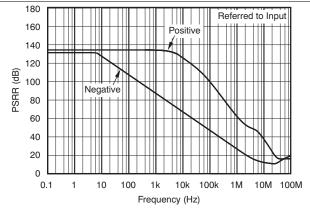
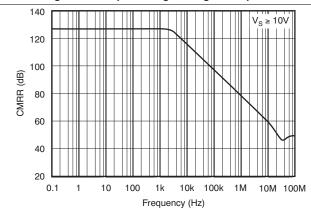


Figure 19. Output Voltage Swing vs Output Current





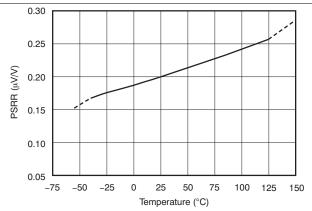
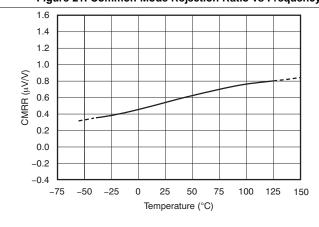


Figure 21. Common-Mode Rejection Ratio vs Frequency

Figure 22. Power-Supply Rejection Ratio vs Temperature



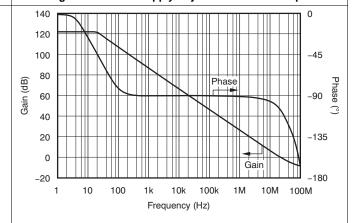


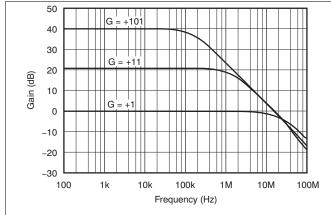
Figure 23. Common-Mode Rejection Ratio vs Temperature

Figure 24. Open-Loop Gain and Phase vs Frequency

TEXAS INSTRUMENTS

Typical Characteristics (continued)

At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



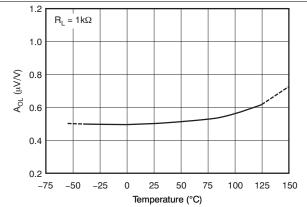
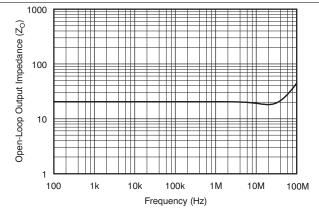


Figure 25. Closed-Loop Gain vs Frequency

Figure 26. Open-Loop Gain vs Temperature



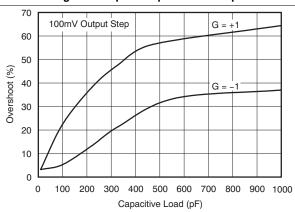
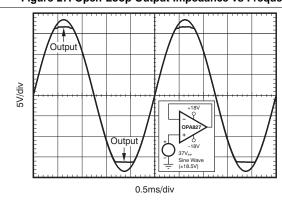


Figure 27. Open-Loop Output Impedance vs Frequency

Figure 28. Small-Signal Overshoot vs Capacitive Load



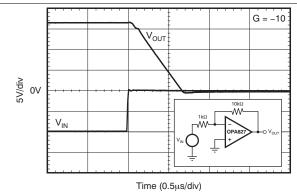


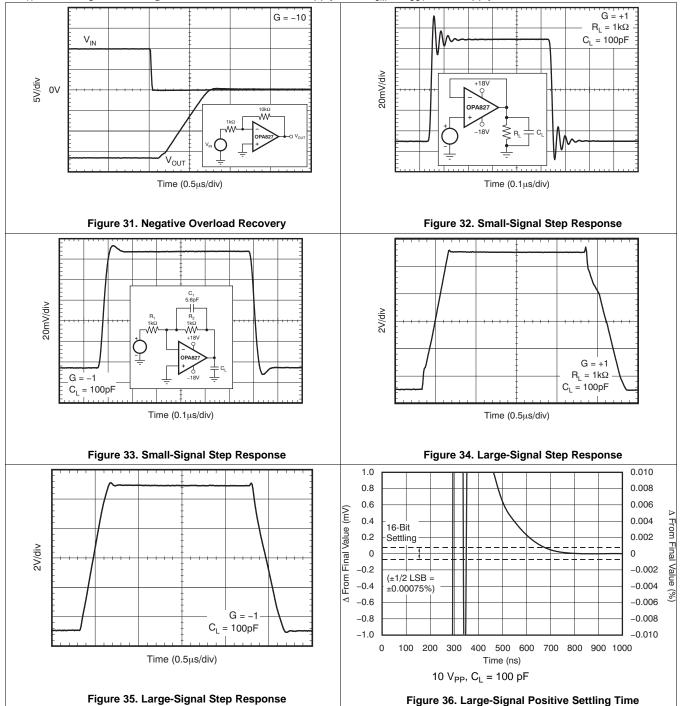
Figure 29. No Phase Reversal

Figure 30. Positive Overload Recovery



Typical Characteristics (continued)

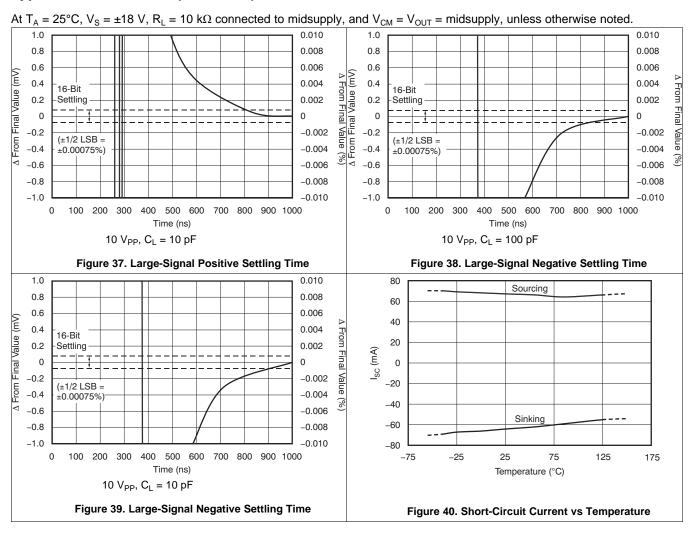
At $T_A = 25$ °C, $V_S = \pm 18$ V, $R_L = 10$ k Ω connected to midsupply, and $V_{CM} = V_{OUT} =$ midsupply, unless otherwise noted.



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TEXAS INSTRUMENTS

Typical Characteristics (continued)



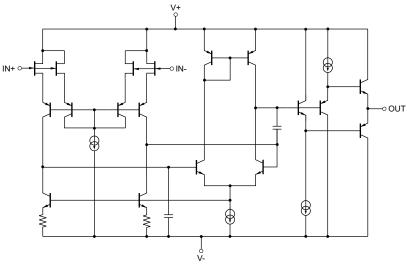


7 Detailed Description

7.1 Overview

The OPA827 is a unity-gain stable, precision operational amplifier with very low noise, input bias current, and input offset voltage. Applications with noisy or high-impedance power supplies require decoupling capacitors placed close to the device pins. In most cases, 0.1-µF capacitors are adequate.

7.2 Functional Block Diagram



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7.3 Feature Description

The OPA827 is a precision JFET amplifier with low input offset voltage, low input offset voltage drift and low noise. High impedance inputs make the OPA827 ideal for high source impedance applications and transimpedance applications.

7.3.1 Operating Voltage

The OPA827 series of op amps can be used with single or dual supplies from an operating range of $V_S = 8 \text{ V } (\pm 4 \text{ V})$ and up to $V_S = 36 \text{ V } (\pm 18 \text{ V})$. This device does not require symmetrical supplies; it only requires a minimum supply voltage of 8 V. Supply voltages higher than 40 V ($\pm 20 \text{ V}$) can permanently damage the device; see *Absolute Maximum Ratings*. Key parameters are specified over the operating temperature range, $T_A = -40^{\circ}\text{C}$ to 125°C. Key parameters that vary over the supply voltage or temperature range are shown in *Typical Characteristics* of this data sheet.

7.3.2 Noise Performance

Figure 41 shows the total circuit noise for varying source impedances with the operational amplifier in a unity-gain configuration (with no feedback resistor network and therefore no additional noise contributions). The OPA827 (GBW = 22 MHz) and OPA211 (GBW = 80 MHz) are both shown in this example with total circuit noise calculated. The op amp itself contributes both a voltage noise component and a current noise component. The voltage noise is commonly modeled as a time-varying component of the offset voltage. The current noise is modeled as the time-varying component of the input bias current and reacts with the source resistance to create a voltage component of noise. Therefore, the lowest noise op amp for a given application depends on the source impedance. For low source impedance, current noise is negligible, and voltage noise generally dominates. The OPA827 family has both low voltage noise and lower current noise because of the FET input of the op amp. Very low current noise allows for excellent noise performance with source impedances greater than 10 k Ω . OPA211 has lower voltage noise and higher current noise. The low voltage noise makes the OPA211 a better choice for low source impedances (less than 2 k Ω). For high source impedance, current noise may dominate, and makes the OPA827 series amplifier the better choice.

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The equation in Figure 41 shows the calculation of the total circuit noise, with these parameters:

- e_n = voltage noise
- i_n = current noise
- R_S = source impedance
- $k = Boltzmann's constant = 1.38 \times 10^{-23} J/K$
- T = temperature in kelvins

For more details on calculating noise, see Basic Noise Calculations.

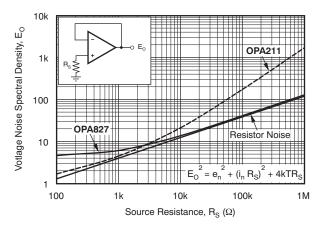


Figure 41. Noise Performance of the OPA827 and OPA211 in Unity-Gain Buffer Configuration

7.3.3 Basic Noise Calculations

Low-noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases; consider the effect of source resistance on the overall noise performance of the op amp. Total noise of the circuit is the root-sum-square combination of all noise components.

The resistive portion of the source impedance produces thermal noise proportional to the square root of the resistance. This function is plotted in Figure 41. The source impedance is usually fixed; consequently, select the op amp and the feedback resistors to minimize the respective contributions to the total noise.

Figure 42 illustrates both noninverting (A) and inverting (B) op amp circuit configurations with gain. In circuit configurations with gain, the feedback network resistors also contribute noise. The current noise of the op amp reacts with the feedback resistors to create additional noise components.

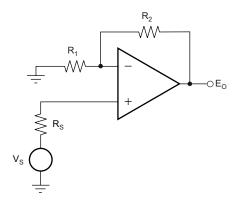
The feedback resistor values can generally be chosen to make these noise sources negligible.

NOTE

Low-impedance feedback resistors load the output of the amplifier. The equations for total noise are shown for both configurations shown in both configurations in Figure 42.



A) Noise in Noninverting Gain Configuration

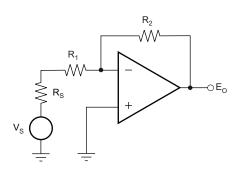


Noise at the output:

$$\begin{split} E_{O}^{\ 2} = & \left[1 + \frac{R_{2}}{R_{1}}\right]^{2} \, e_{n}^{\ 2} + e_{1}^{\ 2} + e_{2}^{\ 2} + \left(i_{n}R_{2}\right)^{2} + e_{S}^{\ 2} + \left(i_{n}R_{S}\right)^{2} \left[1 + \frac{R_{2}}{R_{1}}\right]^{2} \end{split}$$
 Where $e_{S} = \sqrt{4kTR_{S}} \cdot \left[1 + \frac{R_{2}}{R_{1}}\right] = \text{thermal noise of } R_{S}$
$$e_{1} = \sqrt{4kTR_{1}} \cdot \left[\frac{R_{2}}{R_{1}}\right] = \text{thermal noise of } R_{1}$$

$$e_{2} = \sqrt{4kTR_{2}} = \text{thermal noise of } R_{2}$$

B) Noise in Inverting Gain Configuration



Noise at the output:

$$E_{O}^{2} = \left[1 + \frac{R_{2}}{R_{1} + R_{S}}\right]^{2} e_{n}^{2} + e_{1}^{2} + e_{2}^{2} + (i_{n}R_{2})^{2} + e_{S}^{2}$$
Where $e_{S} = \sqrt{4kTR_{S}}$, $\left[\frac{R_{2}}{R_{1} + R_{S}}\right]$ = thermal noise of R_{S}

$$e_{1} = \sqrt{4kTR_{1}}$$
, $\left[\frac{R_{2}}{R_{1} + R_{S}}\right]$ = thermal noise of R_{1}

$$e_{2} = \sqrt{4kTR_{2}}$$
 = thermal noise of R_{2}

For the OPA827 series op amps at 1kHz, $e_n = 4nV/\sqrt{Hz}$ and $i_n = 2.2fA/\sqrt{Hz}$.

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Figure 42. Noise Calculation in Gain Configurations

7.3.4 Total Harmonic Distortion Measurements

The OPA827 series op amps have excellent distortion characteristics. THD + Noise is below 0.0001% (G = +1, $V_O = 3$ V_{RMS}) throughout the audio frequency range, 20 Hz to 20 kHz, with a 600- Ω load (see Figure 3).

The distortion produced by the OPA827 series is below the measurement limit of many commercially available testers. However, a special test circuit (illustrated in Figure 43) can be used to extend the measurement capabilities.

Op amp distortion can be considered an internal error source that can be referred to the input. Figure 43 shows a circuit that causes the op amp distortion to be 101 times greater than that distortion normally produced by the op amp. The addition of R_3 to the otherwise standard noninverting amplifier configuration alters the feedback factor or noise gain of the circuit. The closed-loop gain is unchanged, but the feedback available for error correction is reduced by a factor of 101, thus extending the resolution by 101.

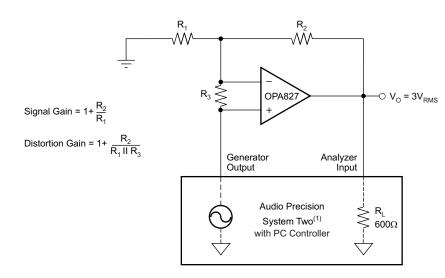
NOTE

the input signal and load applied to the op amp are the same as with conventional feedback without R_3 . The value of R_3 must be kept small to minimize its effect on the distortion measurements.

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The validity of this technique can be verified by duplicating measurements at high gain and high frequency where the distortion is within the measurement capability of the test equipment. Measurements for this data sheet were made with an Audio Precision System Two distortion and noise analyzer, which greatly simplifies such repetitive measurements. This measurement technique, however, can be performed with manual distortion measurement instruments.



| SIGNAL GAIN | DISTORTION GAIN | R ₁ | R_2 | R_3 |
|----------------|--------------------|----------------|-------|-------|
| 1 | 101 | œ | 1kΩ | 10Ω |
| 11 | 101 | 100Ω | 1kΩ | 11Ω |

NOTE: (1) Measurement BW = 80kHz.

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Figure 43. Distortion Test Circuit

7.3.5 Capacitive Load and Stability

The combination of gain bandwidth product (GBW) and near constant open-loop output impedance (Z_O) over frequency gives the OPA827 the ability to drive large capacitive loads. Figure 44 shows the OPA827 connected in a buffer configuration (G = +1) while driving a 2.2- μ F ceramic capacitor (with an ESR value of approximately 0 Ω). The small overshoot and fast settling time are results of good phase margin. This feature provides superior performance compared to the competition. Figure 44 and Figure 45 were taken without any resistive load in parallel to shorten the ringing time.

In Figure 45, the OPA827 is driving a 2.2-µF tantalum capacitor. A relatively small ESR that is internal to the capacitor additionally improves phase margin and provides an output waveform with no ringing and minimal overshoot. Figure 45 shows a stable system that can be used in almost any application.

Capacitive load drive depends on the gain and overshoot requirements of the application. Capacitive loads limit the bandwidth of the amplifier. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads (see Figure 28).

7.3.6 Phase-Reversal Protection

The OPA827 family has internal phase-reversal protection. Many FET-input op amps exhibit a phase reversal when the input is driven beyond its linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input circuitry of the OPA827 prevents phase reversal with excessive common-mode voltage; instead, the output limits into the appropriate rail (see Figure 29).



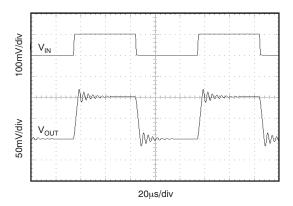


Figure 44. OPA827 Driving 2.2-µF Ceramic Capacitor

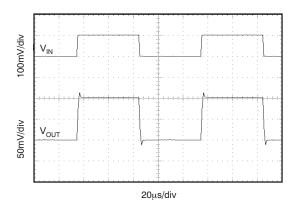


Figure 45. OPA827 Driving 2.2-µF Tantalum Capacitor

7.3.7 Transimpedance Amplifier

The gain bandwidth, low voltage noise, and current noise of the OPA827 series make them ideal wide bandwidth transimpedance amplifiers in a photo-conductive application. High transimpedance gains with feedback resistors greater than 100 k Ω benefit from the low input current noise (2.2 fA/Hz) of the JFET input. Low voltage noise is important because photodiode capacitance causes the effective noise gain in the circuit to increase at high frequencies. Total input capacitance of the circuit limits the overall gain bandwidth of the amplifier and is addressed below. Figure 46 shows a photodiode transimpedance application.

7.3.7.1 Key Transimpedance Points

- The total input capacitance (C_{TOT}) consists of the photodiode junction capacitance, and both the common-mode and differential input capacitance of the operational amplifier.
- The desired transimpedance gain, $V_{OUT} = I_D R_F$.
- The Unity Gain Bandwidth Product (UGBW) (22 MHz for the OPA827).

With these three variables set, the feedback capacitor value (C_F) can be calculated to ensure stability. C_{STRAY} is the parasitic capacitance of the PCB and passive components, which is approximately 0.5 pF.

To ensure 45° phase margin, the minimal amount of feedback capacitance can be calculated using Equation 1.

$$C_{F}\left(\frac{1}{4\pi R_{F}UGBW}\right)\left(1+\sqrt{1+\left(8\pi C_{TOT}R_{F}UGBW\right)}\right) \tag{1}$$

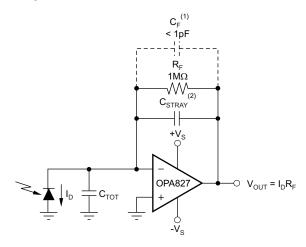
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Bandwidth (f_{-3dB}) can be calculated using Equation 2.

$$f_{-3dB} = \sqrt{\frac{UGBW}{2\pi R_F(C_{TOT})}} Hz$$
 (2)

These equations result in maximum transimpedance bandwidth. For additional information, refer to *Compensate Transimpedance Amplifiers Intuitively*, available for download at www.ti.com.



NOTES: (1) C_F is optional to prevent gain peaking. (2) C_{STRAY} is the stray capacitance of R_F (typically, 2pF for a surface-mount resistor). Copyright © 2016, Texas Instruments Incorporated

Figure 46. Transimpedance Amplifier

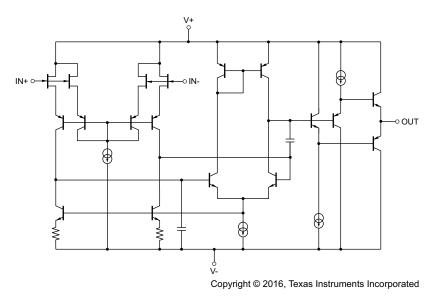


Figure 47. Equivalent Schematic (Single-Channel)

7.4 Device Functional Modes

The OPA827 has a single functional mode and is operational when the power-supply voltage is greater than 4 V (±2 V). The maximum power supply voltage for the OPA827 is 36 V (±18 V).



8 Application and Implementation

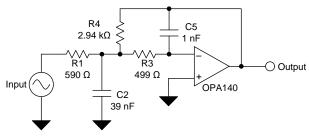
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA827 is a unity-gain stable, operational amplifier with very low noise, input bias current, and input offset voltage. Applications with noisy or high-impedance power supplies require decoupling capacitors placed close to the device pins. In most cases, 0.1-µF capacitors are adequate. Designers can easily take advantage of the low-noise characteristics of JFET amplifiers while also interfacing to modern, single-supply, precision data converters.

8.2 Typical Application



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Figure 48. 25-kHz Low-Pass Filter

8.2.1 Design Requirements

Low-pass filters are commonly employed in signal processing applications to reduce noise and prevent aliasing. The OPA827 is ideally suited to construct high-speed, high-precision active filters. Figure 48 shows a second-order, low-pass filter commonly encountered in signal processing applications.

Use the following parameters for this design example:

- Gain = 5 V/V (inverting gain)
- Low-pass cutoff frequency = 25 kHz
- Second-order Chebyshev filter response with 3-dB gain peaking in the pass band

8.2.2 Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in. Use Equation 3 to calculate the voltage transfer function.

$$\frac{\text{Output}}{\text{Input}}(s) = \frac{-1/R_1 R_3 C_2 C_5}{s^2 + (s/C_2)(1/R_1 + 1/R_3 + 1/R_4) + 1/R_3 R_4 C_2 C_5}$$
(3)

This circuit produces a signal inversion. For this circuit, the gain at DC and the low-pass cutoff frequency are calculated by Equation 4.

Gain =
$$\frac{R_4}{R_1}$$

 $f_C = \frac{1}{2\pi} \sqrt{(1/R_3 R_4 C_2 C_5)}$ (4)

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Typical Application (continued)

Software tools are readily available to simplify filter design. WEBENCH® Filter Designer is a simple, powerful, and easy-to-use active filter design program. WEBENCH® Filter Designer lets you create optimized filter designs using a selection of TI operational amplifiers and passive components from TI's vendor partners.

Available as a web based tool from the WEBENCH Design Center, WEBENCH Filter Designer allows you to design, optimize, and simulate complete multistage active filter solutions within minutes.

8.2.3 Application Curve

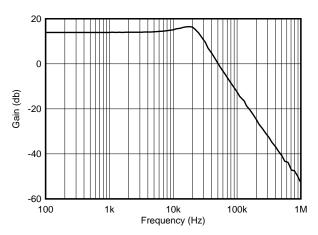


Figure 49. OPA827 Second-Order, 25-kHz, Chebyshev, Low-Pass Filter

8.3 System Examples

The OPA827 is well-suited for phase-lock loop (PLL) applications because of the low voltage offset, low noise, and wide gain bandwidth. Figure 50 illustrates an example of the OPA827 in this application. The first amplifier (OPA827) provides the loop low-pass, active filter function, while the second amplifier (OPA211) serves as a scaling amplifier. This second stage amplifies the DC error voltage to the appropriate level before it is applied to the voltage-controlled oscillator (VCO).

Operational amplifiers used in PLL applications are often required to have low voltage offset. As with other DC levels generated in the loop, a voltage offset applied to the VCO is interpreted as a phase error. An operational amplifier with inherently low voltage offset helps reduce this source of error. Also, any noise produced by the operational amplifiers modulates the voltage applied to the VCO and limits the spectral purity of the oscillator output. The VCO generates noise-related, random phase variations of its own, but this characteristic becomes worse when the input voltage source noise is included. This noise appears as random sideband energy that can limit system performance. The very low flicker noise (1/f) and current noise (In) of the OPA827 help to minimize the operational amplifier contribution to the phase noise.

Product Folder Links: OPA827

22



System Examples (continued)

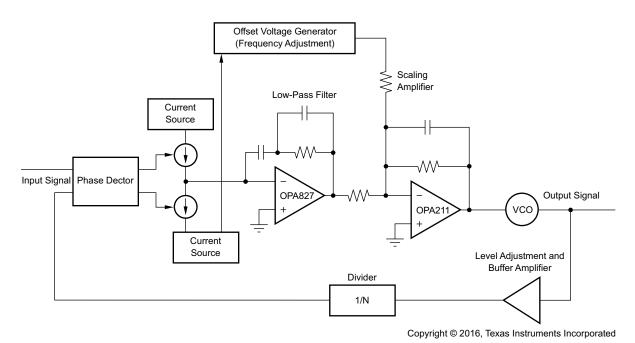


Figure 50. PLL Application

8.3.1 OPA827 Used as an I/V Converter

The OPA827 series of operation amplifiers have low current noise and offset voltage that make these devices a great choice for an I/V converter. DAC8811 is a single-channel, current output, 16-bit digital-to-analog converter (DAC). The I_{OUT} terminal of the DAC is held at a virtual GND potential by the use of the OPA827 as an external I/V converter op amp. The R-2R ladder is connected to an external reference input (V_{REF}) that determines the DAC full-scale current. The external reference voltage can vary in a range of –15 V to 15 V, thus providing bipolar I_{OUT} current operation. By using the OPA827 as an external I/V converter in conjunction with the internal DAC8811 R_{FB} resistor, output voltage ranges of $-V_{REF}$ to $+V_{REF}$ can be generated.

When using an external I/V converter and the DAC8811 R_{FB} resistor, the DAC output voltage is given by Equation 5.

$$V_{\text{OUT}} = \frac{-V_{\text{REF}} \times \text{CODE}}{65536}$$
NOTE
CODE is the digital input into the DAC.

The DAC output impedance as seen looking into the I_{OUT} terminal changes versus code. The low offset voltage of the OPA827 minimizes the error propagated from the DAC.

For a current-to-voltage design (see Figure 51), the DAC8811 I_{OUT} pin and the inverting node of the OPA827 must be as short as possible and adhere to good PCB layout design. For each code change on the output of the DAC, there is a step function. If the parasitic capacitance is excessive at the inverting node, then gain peaking is possible. For circuit stability, two compensation capacitors, C_1 and C_2 (4 pF to 20 pF typical) can be added to the design.

Some applications require full four-quadrant multiplying capabilities or a bipolar output swing. As shown in Figure 51, the OPA827 is added as a summing amp and has a gain of 2x that widens the output span to 20 V. A four-quadrant multiplying circuit is implemented by using a 10-V offset of the reference voltage to bias the OPA827.



System Examples (continued)

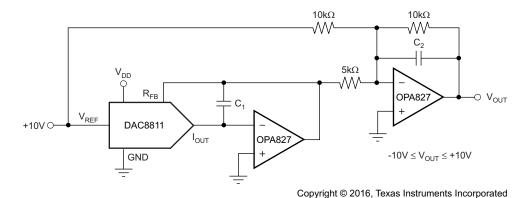


Figure 51. I/V Converter

9 Power Supply Recommendations

The OPA827 is specified for operation from 4 V to 36 V (±2 V to ±18 V); many specifications apply from –40°C to 125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Absolute Maximum Ratings*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute Maximum Ratings*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see *Layout*.



10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground
 planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically
 separate digital and analog grounds paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in Figure 52, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- For best performance, TI recommends cleaning the PCB following board assembly.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the
 plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB
 assembly to remove moisture introduced into the device packaging during the cleaning process. A low
 temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.2 Layout Example

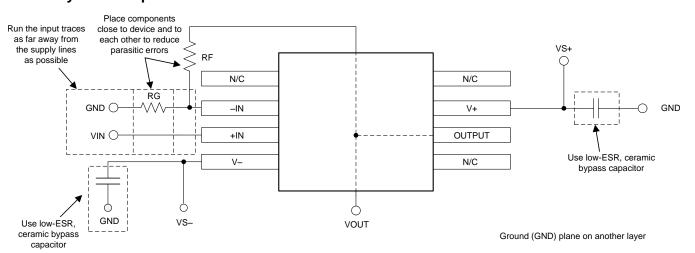


Figure 52. Operational Amplifier Board Layout for Noninverting Configuration



11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

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11.1.2 Development Support

For development support see the following:

- WEBENCH® Filter Designer
- OPA211
- DAC8811

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

Compensate Transimpedance Amplifiers Intuitively (SBOA055)

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resource

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

E2E is a trademark of Texas Instruments.

WEBENCH is a registered trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------|-----------------------|-----|--------------------------------|----------------------------|--------------|------------------|
| OPA827AID | Active | Production | SOIC (D) 8 | 75 TUBE | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |
| OPA827AID.B | Active | Production | SOIC (D) 8 | 75 TUBE | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |
| OPA827AIDG4 | Active | Production | SOIC (D) 8 | 75 TUBE | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |
| OPA827AIDGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | Call TI Nipdauag Nipdau | Level-2-260C-1 YEAR | -40 to 125 | NSP |
| OPA827AIDGKR.B | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | NSP |
| OPA827AIDGKT | Active | Production | VSSOP (DGK) 8 | 250 SMALL T&R | Yes | Call TI Nipdauag Nipdau | Level-2-260C-1 YEAR | -40 to 125 | NSP |
| OPA827AIDGKT.B | Active | Production | VSSOP (DGK) 8 | 250 SMALL T&R | Yes | Call TI | Level-2-260C-1 YEAR | -40 to 125 | NSP |
| OPA827AIDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |
| OPA827AIDR.B | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |
| OPA827AIDRG4 | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | OPA 827 A |

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

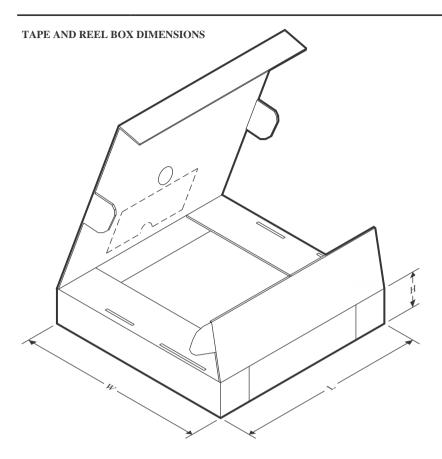
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| OPA827AIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA827AIDGKT | VSSOP | DGK | 8 | 250 | 180.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA827AIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

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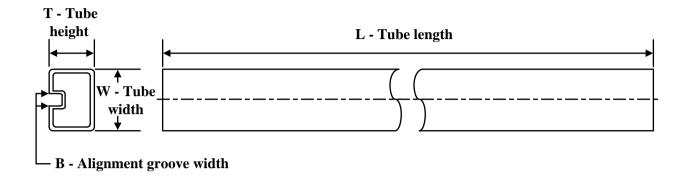
*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA827AIDGKR | VSSOP | DGK | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| OPA827AIDGKT | VSSOP | DGK | 8 | 250 | 213.0 | 191.0 | 35.0 |
| OPA827AIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| OPA827AID | D | SOIC | 8 | 75 | 506.6 | 8 | 3940 | 4.32 |
| OPA827AID.B | D | SOIC | 8 | 75 | 506.6 | 8 | 3940 | 4.32 |
| OPA827AIDG4 | D | SOIC | 8 | 75 | 506.6 | 8 | 3940 | 4.32 |



SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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